#### Amal Elgawadi, PhD in Physics aelgaw01@hotmail.com Location: Cairo, Egypt Mobiles: 0101-537-9377 & 0114-95-00-101

#### **OBJECTIVE:**

Required for accreditation. Experience in teaching and research in physics, spectroscopy, lasers, and photonics including in class and on-line teaching.

#### Education:

- **PhD in Photonics/Physics**, Oklahoma State University, USA. Thesis: Effect of Strain on the Optical Properties of GaN Films, and GaN/AlGaN Heterostructure. Laser Lift-Off for GaN/AlGaN Multilayer.
- **MS in Physics**, Al-Azahr University, Cairo, Egypt. Thesis: Physical characterization of FeSn<sub>2</sub> thin films.
- MS in Electro-Physics, Polytechnic Institute of New York University, USA.
- MS in Physics, Polytechnic Institute of New York University, USA.
- **BS in Physics**, Suez Canal University, Egypt.

#### TEACHING PROFESSIONAL EXPERIENCE:

## High Institute for Engineering and Technology, Egypt

Literature, October 2014 – current -Taught General Physics (Classical Mechanics; Electricity and Magnetism) to preparatory year engineering students

-Taught wave and optics to communications and power engineering students

**Zewail City of Science and Technology**, 6 of October, Egypt **Adjunct faculty**, October 2015 – Jan 2016 -Taught spectroscopy for 3<sup>rd</sup> grade Nano Science and Material Science Students

**King Saud University**, Riyadh, KSA **Assistant Professor**, Jan 2010 – July 2010 -Taught Physics to preparatory year medical students

## Oklahoma State University, Stillwater, OK

#### **Teaching Assistant, 2001**

-Taught & supervised undergraduate students (optical/electrical experiments).

# **Polytechnic Institute of New York University**, NY

**Adjunct Faculty,** 1997 – 1999

-Taught and instructed undergraduate students (electromagnetic experiments).

#### COMPUTER SKILLS:

Hardware: IBM PC, Macintosh

**Operating Systems:** MS-DOS, Windows

Data Acquisition and Automation Software: Lab View

Languages: Q-Basic, True Basic

Multimedia: Macromedia Authorware, Adobe Photoshop, Adobe Premiere

Image and Signal Processing: MatLab (Intimate experience)

Software: Origin, Microsoft Excel, Microsoft Word, Equation Editor, Microsoft PowerPoint, Google

Spreadsheet, Form builder, and Google Form.

Instrument Interfaces: GPIB and RS-232

**Drafting**: AutoCAD (Intimate experience)

## TECHINCAL SKILLS:

Experience in machine shop equipment and operations (Lathe, Mill, etc.).

Workshop in refrigerator maintenance.

Photography, Photoshop and color developing.

## PATENT:

*Amal Elgawadi*, Fabrication of GaN and III-Nitride Alloys Freestanding Epilayers Membranes Using a Nonbonding Laser Lift-off Technique.

US Patent # 8313968 (Nov. 20, 2012)

World Patent Cooperation Treaty # WO/2009/026366.

Egypt Patent # 25851, Sep. 2012.

#### **RESEARCH EXPERIENCE:**

Current
Editing research papers
Department of Physics
King Saud University
Assistant Professor Jan 2010 – July 2010
Research on group III-nitrides.
Department of Electrical and Computer Engineering
Oklahoma State University
<b>Research</b> 2006 – 2009
Research on group III-nitride.
Research Associate Jan 2007 – Dec 31, 2007
Photonics Specialist Aug 2006 – Dec 2006

#### Center for Laser and Photonics Research & Department of Electrical and Computer Engineering Oklahoma State University, Stillwater, OK Descense Assistant, 2000, 2005

**Research Assistant,** 2000 – 2005

- Fabricated freestanding nanoheterostructure membranes using nonbonding laser lift-off (NBLLO) technique.
- Separated GaN epilayers using laser lift-off (LLO) technique.
- Designed optical systems to determine the optical characterizations of semiconductors, such as Wide-band gap semiconductors (Al, Ga, P) III-nitrides and ZnO, grown for Light Emitted Diode (LED), Laser Diode (LD) and High Electron Mobility Transistors (HEMT) applications.
- Constructed, performed, and analyzed data from temperature dependent low-power-lasers experiments such as photoluminescence, reflectance, absorption, and photoabsorption.

Vitae, Amal Elgawadi, PhD Physics

- Built, achieved, and evaluated data from temperature dependent high-power-lasers experiments, such as, stimulated emission, and photoabsorption.
- Operated a wide variety of equipment such as *cw* and ultrafast laser spectroscopy (HeCd, Ar+, Nd:YAGs, Excimer), optoelectronics detection devices (CCD, PMT, photodiode), spectrometers, broadband optical sources and lock-in amplifiers.
- Determined optical properties of group III-nitride and ZnO bulk and thin films and GaN/AlGaN heterostructure.
- Communicated with engineers and technicians during equipment troubleshooting.
- Set up work and purchase orders.

## **RESEREACH PROJECTS:**

## **Doctoral Projects:**

## Center for Laser and Photonics Research, Oklahoma State University, Stillwater, OK

- Microelectronics Fabrication Lab: Fabricated THz microchips through a comprehensive lab course, including cleanrooms protocol, photolithography, etching, metal deposition, etc.
- Achieved terahertz time-domain spectroscopy (THz-TDS) measurements.
- Designed and tested a Q-switching laser.

## Master's Research Projects:

# **Polytechnic Institute of New York University**, NY

- Designed a virtual instrument using LabView to control the power of a laser diode and analyze the output of a microsphere-fiber optic coupler (Lab internship).
- Performed image and signal processing simulation experiments using MatLab.
- Developed an interactive multimedia program using Authorware.
- Assisted in building an Ultra High Vacuum Scanning Tunneling Microscope (UHV-STM).
- Performed computational methods and computer simulation analysis.

## Additional Research Projects and Experience:

- Designed Ellipsometer and determined the optical constants for FeSn<sub>2</sub> thin films.
- Electrical: Measurements of V-I for *CdSSe/CdTe* solar cells. Analysis of data from Capacitance Voltage (C-V) and Hall mobility measurements.
- Determined optical constants of lead glass.
- Completed a scanning electron microscope SEM course and lab (theory and lab).
- Attended transmission electron microscope TEM course and lab (unofficial audit).
- Thin films structure and characterization: X-Ray Diffraction (XRD).
- Pictured the topography of mica film and determined its thickness via interference fringes.

## PROFESSIONAL MEMBERSHIPS:

American Physical Society Optical Society of America SPIE (The International Society for Optical Engineering)

## AWARDS:

Lynn T Miller Scholarship, 2004-2005

Oklahoma State University, Electrical Engineering Fellowship, 2002-2004

Oklahoma State University, Arts and Sciences Fellowship, 2000-2002

#### LEADERSHIP & PERSONAL:

Leading a team of teaching assistants both in physics labs and tutorial sessions. Guided graduate students. Directed and supervised technicians. Proposal writing, presentation, and communication skills. Goaloriented, team player, self-motivated, independent worker. Organizational and documentation skills. *Fluency in English (teaching 99% of the topics in English in Egypt and the Kingdom of Saudi Arabia).* 

#### PUBLICATIONS:

- <u>Amal Elgawadi</u>, Gordon Gainer, and Jerzy Krasinski, "The convergence of longitudinal excitons onto the Γ5 transverse exciton in GaN and the thermal activation energy of longitudinal excitons," J. Phys.: Condens. Matter 25, 335803 (2013).
- <u>Amal Elgawadi</u>, and J. Krasinski, "Strain at the Surface of GaN Epilayers and at GaN/Sapphire Interface before and after Laser Lift-off (LLO) from the Sapphire Substrate," J. Appl. Phys., 103, 033519 (2008).
- 3. <u>Amal Elgawadi</u>, J. Krasinski, G. Gainer, Alexander Usikov, and V. Dmitriev, "Modification of the anomalous optical transitions in multilayer AlGaN-based nanoheterostructure using a nonbonding laser lift-off technique," J. Appl. Phys., **103**, 123512 (2008).
- <u>Amal Elgawadi</u>, J. Krasinski, G. Gainer, and V. Dmitriev, "Modification of the Anomalous "V-shaped" and "S-shaped" Temperature Dependent Photon Energy in Al<sub>x</sub>Ga<sub>1-x</sub>N/GaN (0<x≤38) Nanoheterostructures Using a Nonbonding Laser Lift off (NBLLO) Technique," Proc. SPIE 6894, 689421 (2008).
- Zhen Jiang, Guan Xu, <u>Amal Elgawadi</u>, and Daqing Piao, "Development of a Trans-Rectal Optical Tomography Probe for Concurrent Sagittal Imaging with Trans-Rectal Ultrasound," Optical Society of America, Biomedical Optics, Instrumentation and Techniques for Tissue Imaging (BWG) (2008).
- J. B. Lam, G. H. Gainer, S. Bidnyk, <u>Amal Elgawadi</u>, G. H. Park, J. Krasinski, J. J. Song, D. V. Tsvetkov, and V. A. Dmitriev, "Comparative study of HVPE- and MOCVD-grown nitride structures for UV lasing application," *Int. J. Nitride Semicond*. (2001).
- J. B. Lam, G. H. Gainer, S. Bidnyk, <u>Amal Elgawadi</u>, G. H. Park, J. Krasinski, J. J. Song, D. V. Tsvetkov, and V. A. Dmitriev, "Comparative study of HVPE- and MOCVD-grown nitride structures for UV lasing application," *Mat. Res. Soc. Symp. Proc.*, G6.4 (2000).

## Manuscripts or in preparation:

- 1. <u>Amal Elgawadi</u> et al., "Variations of crystal and surface lattice parameters of as-grown and FS GaN."
- 2. <u>Amal Elgawadi</u> et al., "Investigation of Debye temperatures of GaN."
- 3. <u>Amal Elgawadi</u> et al., "Fabrication of Freestanding AlGaN Nanoheterostructure Membrane by Nonbonding Laser Lift-off (NBLLO) Technique."
- 4. <u>Amal Elgawadi</u> et al., "C-V and PL Investigations of the Effects of the Piezoelectric Field and the Strain on the Electron Mobility in *Al*<sub>0.22</sub>*Ga*<sub>0.78</sub>*N*/*GaN* Heterostructure Grown for High Electron Mobility Transitions (HEMTs) Applications."
- 5. <u>Amal Elgawadi</u> et al., "Strong Two Components Longitudinal Phonon (LO) -Replicas in *GaN/AlGaN* Heterostructure."
- 6. <u>Amal Elgawadi</u> et al., "Nonradiative Recombination Effects on the Deep Ultra Violet emission in AlGaN/GaN Heterostructure."
- 7. <u>Amal Elgawadi</u> et al., "Transmission and reflection of AlGaN epilayers."
- 8. <u>Amal Elgawadi</u> et al., "Investigation of the photoquenching in *ZnO* by means of photoluminescence and photoabsorption techniques."